

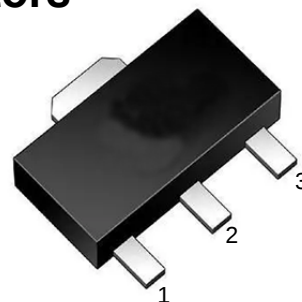
SOT-89-3L Plastic-Encapsulate Transistors

BCX51

TRANSISTOR (PNP)

• Features

- Compliment to BCX54
- Low Voltage
- High Current



1. BASE
2. COLLECTOR
3. EMITTER

SOT-89-3L

• MAXIMUM RATINGS

 ($T_C=25^{\circ}\text{C}$)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	-45	V
Collector-Emitter Voltage	V_{CEO}	-45	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-1	A
Collector Power Dissipation	P_C	500	mW
Thermal Resistance From Junction To Ambient	$R_{\theta JA}$	250	$^{\circ}\text{C/W}$
Operation Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	$^{\circ}\text{C}$

• ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-100\mu\text{A}, I_E=0$	-45			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}^*$	$I_C=-10\text{mA}, I_B=0$	-45			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-100\mu\text{A}, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB}=-30\text{V}, I_E=0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$			-0.1	μA
DC current gain	$h_{FE(1)}^*$	$V_{CE}=-2\text{V}, I_C=-5\text{mA}$	63			
	$h_{FE(2)}^*$	$V_{CE}=-2\text{V}, I_C=-150\text{mA}$	63		250	
	$h_{FE(3)}^*$	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}^*$	$I_C=-0.5\text{A}, I_B=-50\text{mA}$			-0.5	V
Base-emitter voltage	V_{BE}^*	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$			-1	V
Transition frequency	f_T	$V_{CE}=-5\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$		50		MHz

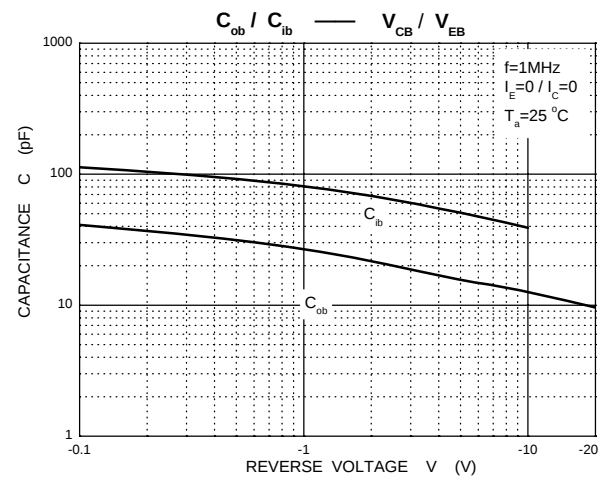
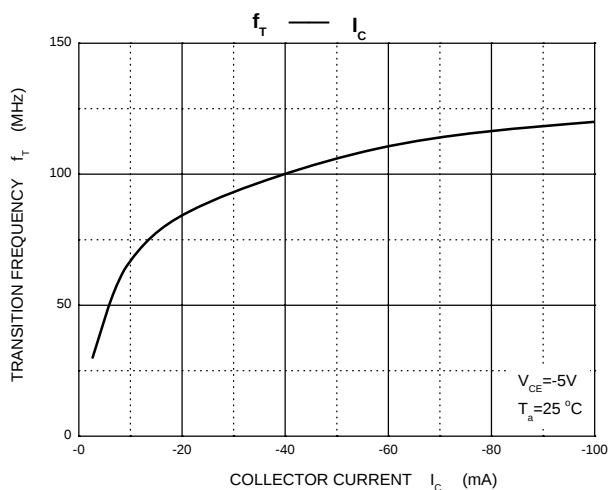
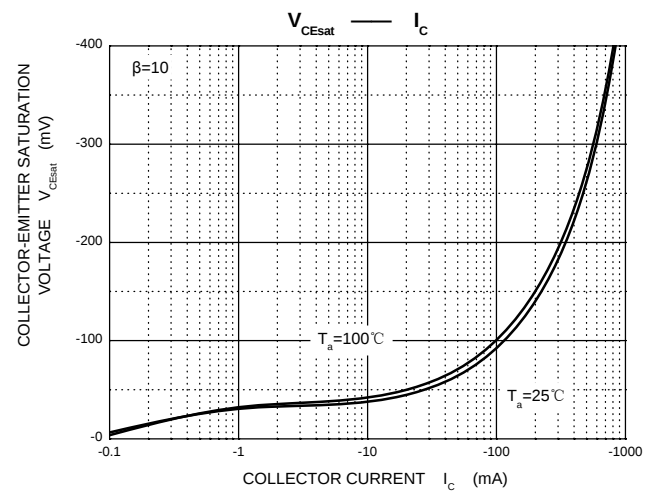
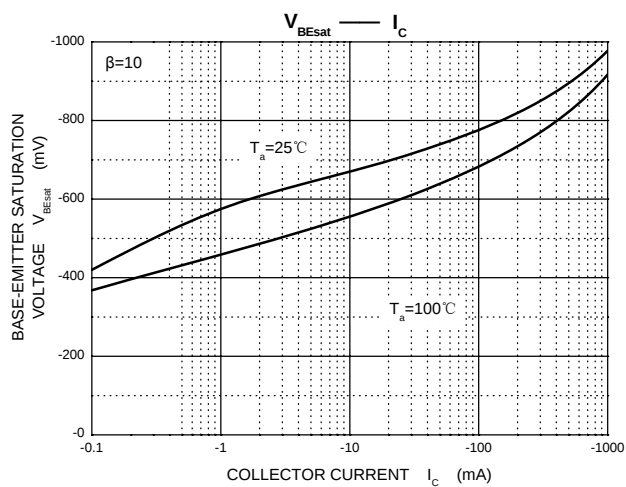
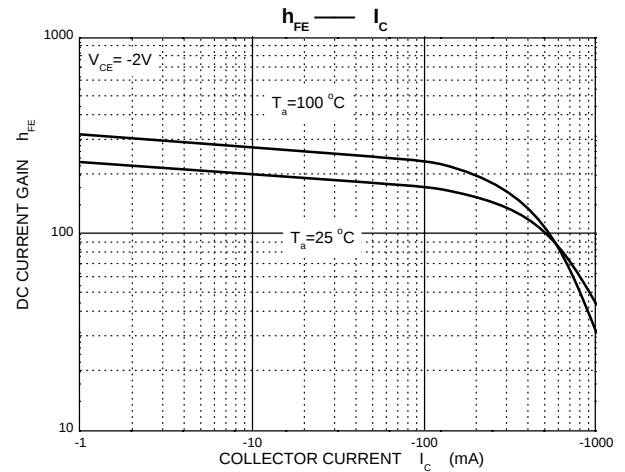
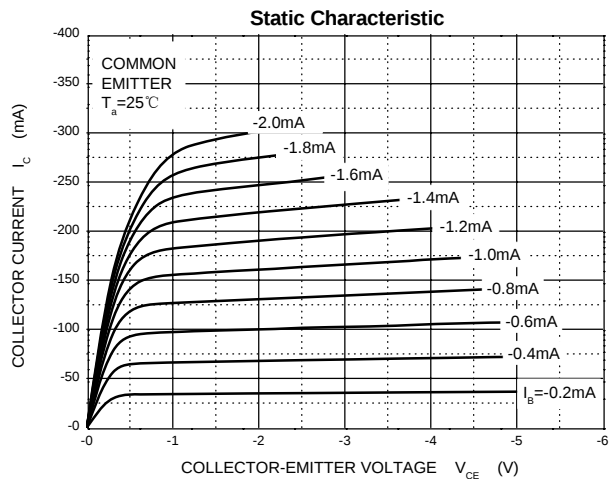
• CLASSIFICATION OF $h_{FE(1)}$

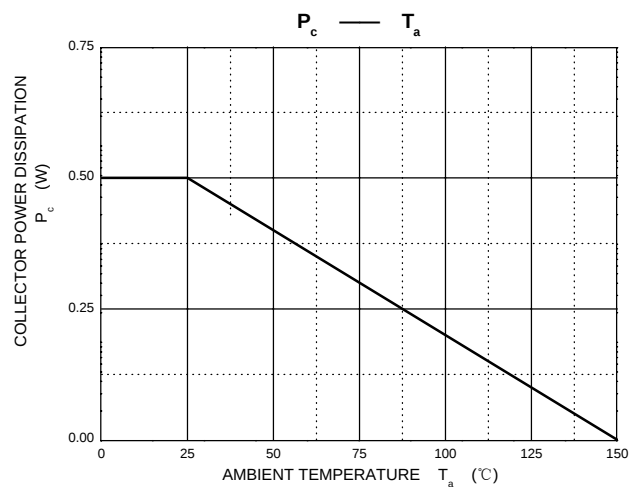
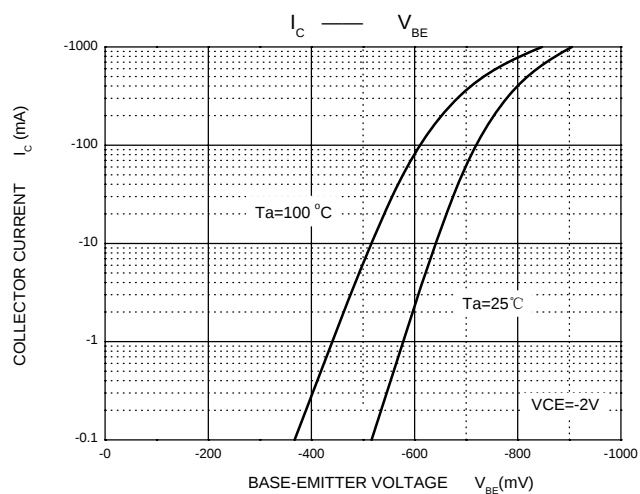
Rank	BCX51	BCX51-10	BCX51-16
Range	63-250	63-160	100-250

• Ordering Information:

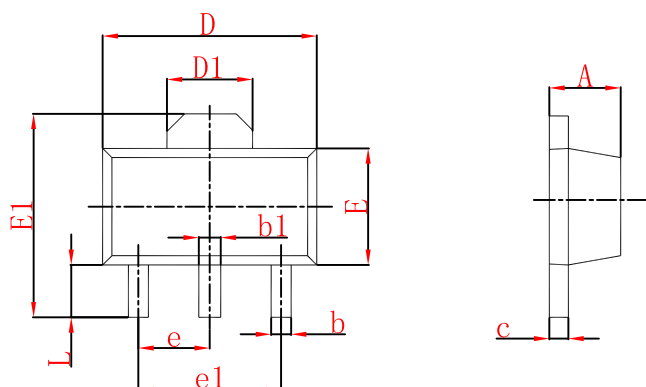
Part NO.	BCX51
Marking	AA/AC/AD
Packing Information	REEL TAPE
Basic ordering unit (pcs)	1000

• Typical Characteristics

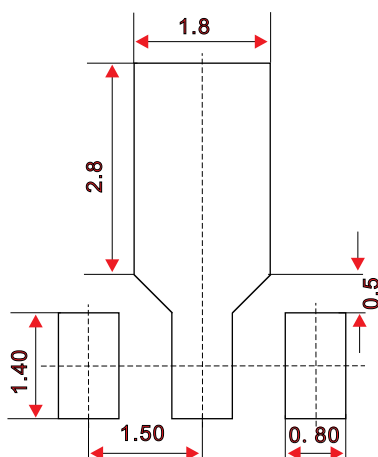




SOT-89-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF.		0.061 REF.	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP.		0.060 TYP.	
e1	3.000 TYP.		0.118 TYP.	
L	0.900	1.200	0.035	0.047



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.